

TRIAC series

1 Description

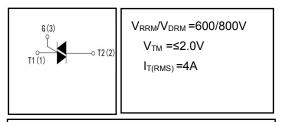
Z0409 series triacs with low holding and latchingcurrent are especially recommended for use onmiddle and small resistance type power load.

2 Features

- High current output up to 4A
- Low Peak on-state voltage drop
- High voltage
- High reliability

3 Applications

- jet pumps of dishwashers
- fans of air-conditioner
- power charger
- AC Motor control





4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25 °C, unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT		
Repetitive peak off-state voltage (Tj=25℃)	V _{DRM}	600/800	V		
Repetitive peak reverse voltage (Tj=25°C)	V_{RRM}	600/800	V		
Non repetitive surge peak Off-state voltage	V _{DSM}	+ 100	V		
Non repetitive peak reverse voltage	V _{RSM}	+ 100	V		
RMS on-state current		I _{T(RMS)}	4	Α	
	tp=8.3ms		27	А	
Non repetitive surge peak on-state current	tp=10ms	I _{TSM}	25		
I ² t value for fusing (tp=10ms)		l ² t	3.1	Α	
Repetitive rate of rise of on-state current	I - II -III		50		
(ITM=20A IG=50mA dIG/dt 50mA/ms)	IV	d _{IT/dt}	10	A/us	
Peak gate current	I _{GM}	1	Α		
Peak gate power	P _{GM}	5	W		
Average gate power dissipation	P _{G(AV)}	0.5	W		
Operating junction temperature range	TJ	- 40 ~ 150	℃		
Storage junction temperature range	T _{STG}	- 40 ~ 150	$^{\circ}$		

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE	UNIT
Thermal Resistance, Junction to Case-sink	R _{thJC}	4.0	°C/W



4.3 Electrical Characteristics (To	c=25°C,unless otherwise noted)
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SYMBOL	PARAMETER	Test Conditions		Min	Тур	Max	Unit
			I - II -III	-	-	10	
I _{GT}	Triggering gate current	$V_D=12V R_L=33\Omega$	IV	-	-	10	mA
V_{GT}	Triggering gate voltage		ALL	-	0.75	1.5	V
V_{GD}	Non-triggering gate voltage	$V_D = V_{DRM} T_j = 125 ^{\circ} CR_L = 3.3 K\Omega$		0.2	-	-	V
			I -III-IV	-	-	20	
I _L	Latching Current	I _G =1.2I _{GT}	II	-	-	35	mA
I _H	Holding Current	I _T =100mA		-	ı	15	mA
d _{V/dt}	Critical Rate of Rise of Off-state Voltage	V _D =2/3V _{DRM} Gate Open T _j =125°C		5	-	-	V/us
V _{TM}	Peak Forward On-State Voltage	I _{TM} =5.5A tp=380us		-	-	2	V
I _{DRM}	Maximum forward or reverse leakage current		Tj=25℃	-	-	10	uA
I _{RRM}	Maximum reverse leakage current	V _D =V _{DRM} V _R =V _{RRM}	Tj=125℃	-	-	1	mA

5 Typical characteristics diagrams

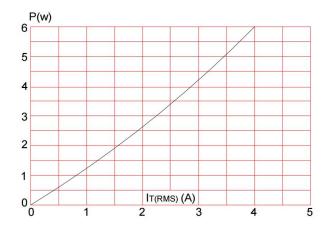


FIG.1: Maximum power dissipation versus RMS on-state current

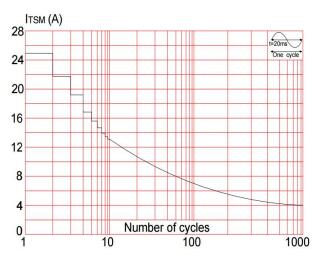


FIG.3: Surge peak on-state current versus number of cycles

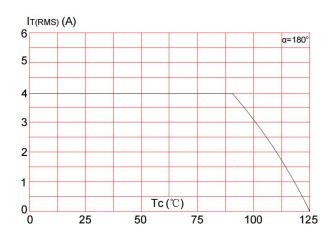


FIG.2: RMS on-state current versus case temperature

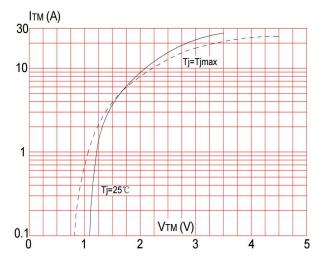
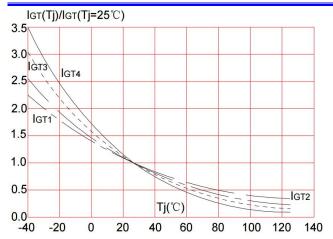


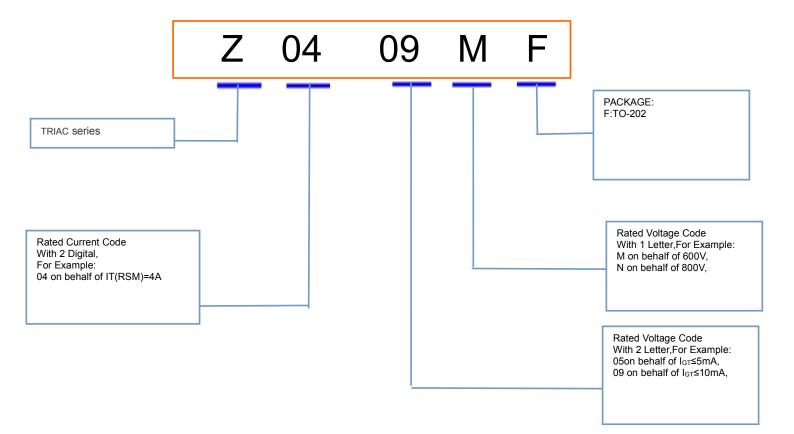
FIG.4: On-state characteristics (maximum values)





and latching current versus junction temperature

6 Product Names Rules

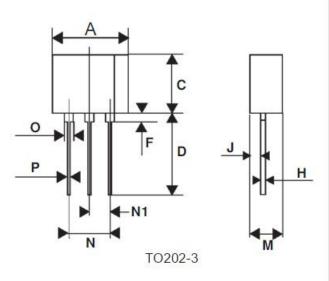


7 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
Z0409MF	TO-202	Z0409MF	Pb-free	Tube	1000//box



8 Dimensions



	DIMENSIONS					
REF.	Millin	neters	Inc	Inches		
	Тур.	Max.	Тур.	Max.		
Α		10.1		0.398		
С	7.3		0.287			
D	10.5		0.413			
E	7.4		0.290			
F		1.5		0.059		
Н	0.51		0.020			
J	1.5		0.059			
M	4.5		0.177			
N		5.3		0.209		
N1	2.54		0.100			
0		1.4		0.055		
Р		0.7		0.028		

9 Attentions

- ROUM Semiconductor Technology CO.,LTD. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of Roma products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

10 Appendix

Revision history:

Date	REV.	Description	Page
2017.08.14	1.0	Original	